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STATEMENT BY APPLICANT**
(Not for submission under 37 CFR 1.99)

Application Number	10594045
Filing Date	2007-06-27
First Named Inventor	Koji Nakayama
Art Unit	2811
Examiner Name	Lynne Ann Gurley
Attorney Docket Number	1217-062849

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CN	4	03038876	WO	A1	2003-05-08	Cree Inc.	<input type="checkbox"/>
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CN	1	BONDOKOV, ROBERT T. ET AL., "Influence of Structural Defects on the Polishing of Silicon Carbide Single Crystal Wafers", Japanese Journal of Applied Physics, Vol. 43, No. 1, 2004, pp. 43-49, Abstract only (1 p.)	<input type="checkbox"/>
CN	2	LENDENMANN, H. ET AL., "High-Power SiC Diodes: Characteristics, Reliability and Relation to Material Defects", Materials Science Forum, Vols. 389-393 (2002), pp. 1259-1264, Trans Tech Publications, Switzerland	<input type="checkbox"/>
CN	3	LEE, K.S. ET AL., "Surface Preparation of 6H-Silicon Carbide Substrates for Growth of High-Quality SiC Epilayers", Materials Science Forum, Vols. 457-460 (2004), pp. 797-800	<input type="checkbox"/>

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